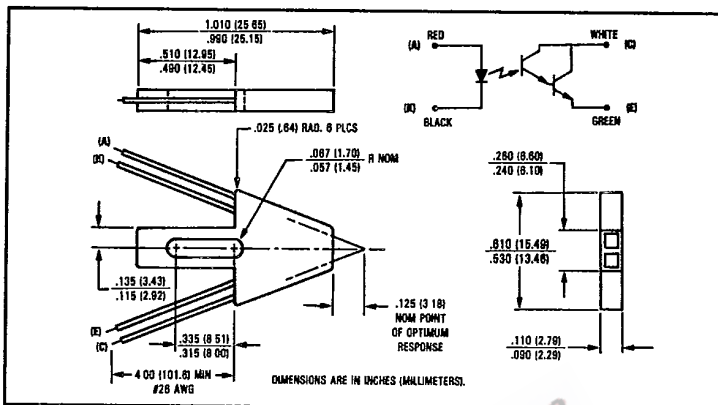
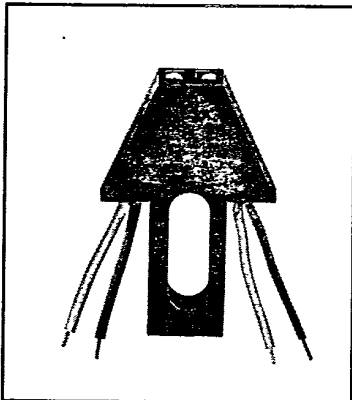


Reflective Object Sensor Type OPB125A



Features

- Photodarlington output
- Low profile to facilitate stacking
- Low cost plastic housing
- 4.0 inches (101.6 mm) minimum length lead wire

Description

The OPB125A consists of an infrared emitting diode and an NPN silicon photodarlington mounted side-by-side on converging optical axes, in a black plastic housing. The photodarlington responds to radiation from the LED only when a reflective object passes within its field of view.

OPB125A utilizes an OP123 or OP223 LED and an OP300 family sensor. Leads are #26 AWG, teflon insulation, 4.0" (101.6 mm) minimum length, stripped and tinned.

Absolute Maximum Ratings (T_A = 25°C unless otherwise noted)

Storage Temperature Range -40°C to +125°C
Operating Temperature Range -40°C to +100°C

Input Diode

Forward DC Current 60 mA
Reverse DC Voltage 2.0 V
Power Dissipation 80 mW⁽¹⁾

Output Photodarlington

Collector-Emitter Voltage 25 V
Emitter-Collector Voltage 5.0 V
Power Dissipation 50 mW⁽²⁾

Notes:

- (1) Derate linearly 1.07 mW/°C above 25°C.
- (2) Derate linearly 0.67 mW/°C above 25°C.
- (3) Measured using an Eastman Kodak neutral white test card having 90% diffuse reflectance as a reflecting surface.
- (4) Measured using a reflecting surface that has a very black dull surface with optical reflectance qualities comparable to a surface coated with carbon black printer's ink.
- (5) Crosstalk (I_{CE}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Lower curve is based on a calculated worst case condition rather than the conventional -2σ limit.
- (7) d is the distance from the assembly head to the reflective surface.

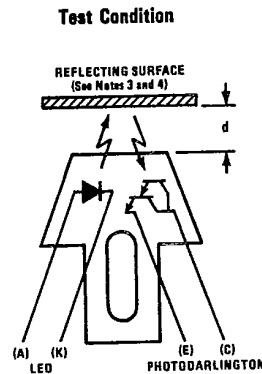
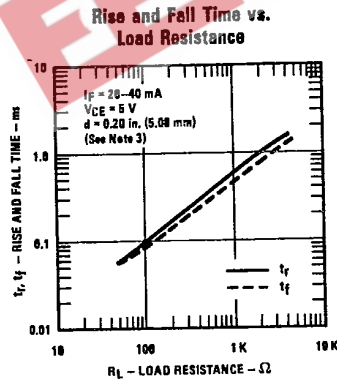
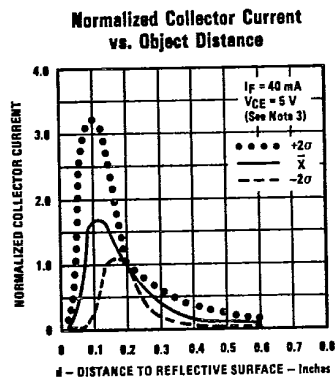
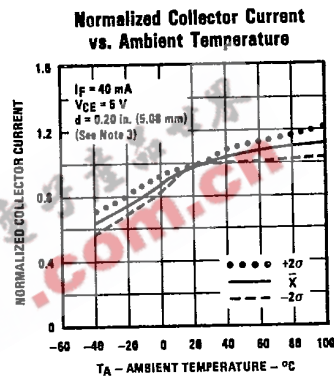
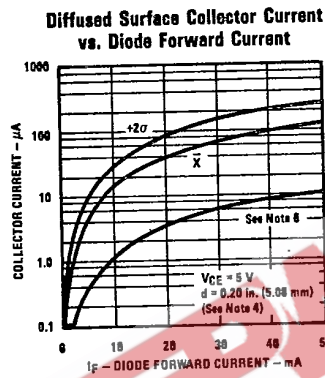
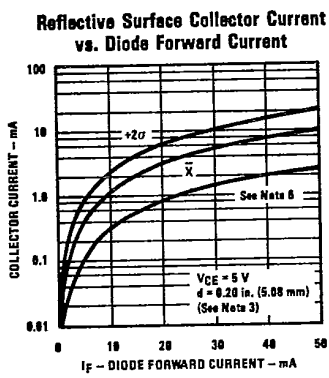
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Type OPB125A

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Min.	Max.	Units	Test Conditions
Input Diode					
V _F	Forward Voltage		1.70	V	I _F = 50 mA
I _R	Reverse Current		100	μA	V _R = 2.0 V
Output Photodarlington					
V _{BRICEO}	Collector-Emitter Breakdown Voltage	25		V	I _C = 100 μA
V _{BRIECO}	Emitter-Collector Breakdown Voltage	5.0		V	I _E = 100 μA
I _{CEO}	Collector Dark Current		1.00	μA	V _{CE} = 10.0 V, I _F = 0, E ₀ ≤ 0.100 μW/cm ²
Combined					
I _{C(O)}	On-State Collector Current	2.0		mA	I _F = 40 mA, V _{CE} = 5.0 V, d = 0.200 in. (5.08 mm) ⁽¹⁾ . See Note 3.
I _{CX}	Crosstalk		20	μA	I _F = 40 mA, V _{CE} = 5.0 V, No Reflecting Surface. See Note 5.
V _{CE(SAT)}	Collector-Emitter Saturation Voltage		1.10	V	I _F = 40 mA, I _C = 1 mA, d = 0.200(5.08mm) ⁽¹⁾⁽²⁾⁽³⁾ .

Typical Performance Curves



TRW reserves the right to make changes at any time in order to improve design and to supply the best product possible.
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